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PATENT NUMBER and
ISSUE DATE

U.S. UTILITY Patent Application

AI NI	APPL NUM 10073066	FILING DATE 02/12/2002	CLASS 438	SUBCLASS 5-1	GAU 2812	EXAMINER [Signature]
**APPLICANTS: Pangrie Suzette; Ngo Minh; Hopper Dawn; You Lu;						
**CONTINUING DATA VERIFIED: THIS APPLN CLAIMS BENEFIT OF 60/268,423 02/14/2001 <i>TN</i>						
** FOREIGN APPLICATIONS VERIFIED: None <i>TN</i>						
PG-PUB		DO NOT PUBLISH <input checked="" type="checkbox"/>		RESCIND <input type="checkbox"/>		
Foreign priority claimed		<input type="checkbox"/> yes <input checked="" type="checkbox"/> no		ATTORNEY DOCKET NO		
35 USC 119 condition met		<input type="checkbox"/> yes <input checked="" type="checkbox"/> no		50432-104		
Verified and Acknowledged Examiner's Initials		<i>TN</i>				
TITLE : Phosphorus treatment of low dielectric constant materials in semiconductor device manufacturing						
U.S. DEPT. OF COM. / PAT. & T.M. PTO-436U/Rev. 12-94						

NOTICE OF ALLOWANCE MAILED		Assistant Examiner	CLAIMS ALLOWED	
			Total Claims	Print Claim for O.G
ISSUE FEE		Primary Examiner	DRAWING	
Amount Due	Date Paid		Sheets Drwg.	Figs. Drwg.
<input type="checkbox"/> TERMINAL DISCLAIMER		PREPARED FOR ISSUE	Application Examiner	
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